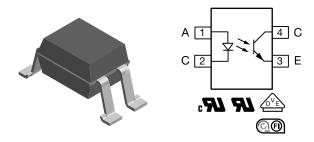
Vishay Semiconductors

Optocoupler, Phototransistor Output, High Reliability, 5300 V_{RMS}



FEATURES

- Excellent CTR linearity depending on forward current
- Pb-free
- Isolation test voltage, 5300 V_{RMS}
- Fast switching times
- Low CTR degradation
- · Low coupling capacitance
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

LINKS TO ADDITIONAL RESOURCES









DESCRIPTION

The SFH615A-3X018T and SFH615A-4X018T features a variety of transfer ratios, low coupling capacitance and high isolation voltage. This coupler has a GaAs infrared diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a plastic SMD package.

The coupling devices are designed for signal transmission between two electrically separated circuits.

APPLICATIONS

- Switchmode power supply
- Telecom
- Battery powered equipment

AGENCY APPROVALS

- UL 1577
- cUL
- DIN EN 60747-5-5 (VDE0884-5) available with option 1
- BSI
- FIMKO

ORDERING INFORMATION s F 6 1 5 Α Χ 0 8 Т SMD-4 PART NUMBER CTR PACKAGE OPTION TAPE BIN AND REEL **CTR (%) AGENCY CERTIFIED / PACKAGE** 10 mA UL. cUL. BSI. FIMKO 100 to 200 160 to 320 SFH615A-3X008T SFH615A-4X008T SMD-4, option 8 UL, cUL, BSI, FIMKO, VDE (option 1) 100 to 200 160 to 320 SMD-4, option 8 SFH615A-3X018T (1) SFH615A-4X018T

Note

(1) Also available in tubes; do not add "T" to end

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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
INPUT					
Reverse voltage		V_R	6	V	
DC forward current		I _F	60	mA	
Surge forward current	t _p ≤ 10 μs	I _{FSM}	2.5	Α	
OUTPUT					
Collector emitter voltage		V _{CEO}	70	V	
Emitter collector voltage		V _{ECO}	7	V	
Collector current		I _C	50	mA	
Collector current	t _p ≤ 1 ms	I _C	100	mA	
COUPLER					
Storage temperature range		T _{stg}	-55 to +150	°C	
Ambient temperature range		T _{amb}	-55 to +100	°C	
Soldering temperature (1)	max. 10 s	T _{sld}	260	°C	

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Refer to reflow profile for soldering conditions for surface mounted devices (SMD)

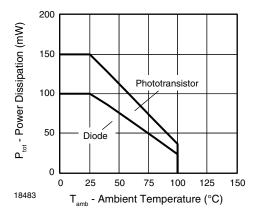


Fig. 1 - Permissible Power Dissipation vs. Ambient Temperature

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THERMAL CHARACTERISTICS			
PARAMETER	SYMBOL	VALUE	UNIT
LED power dissipation	P _{diss}	100	mW
Output power dissipation	P _{diss}	150	mW
Maximum LED junction temperature	T _{jmax.}	125	°C
Maximum output die junction temperature	T _{jmax.}	125	°C
Thermal resistance, junction emitter to board	θ_{EB}	173	°C/W
Thermal resistance, junction emitter to case	$\theta_{\sf EC}$	149	°C/W
Thermal resistance, junction detector to board	θ_{DB}	111	°C/W
Thermal resistance, junction detector to case	θ_{DC}	127	°C/W
Thermal resistance, junction emitter to junction detector	θ_{ED}	95	°C/W
Thermal resistance, board to ambient (1)	θ_{BA}	195	°C/W
Thermal resistance, case to ambient (1)	θ_{CA}	3573	°C/W

Notes

The thermal model is represented in the thermal network below. Each resistance value given in this model can be used to calculate the
temperatures at each node for a given operating condition. The thermal resistance from board to ambient will be dependent on the type of
PCB, layout and thickness of copper traces. For a detailed explanation of the thermal model, please reference Vishay's thermal
characteristics of optocouplers application note.

(1) For 2 layer FR4 board (4" x 3" x 0.062")

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT						
Forward voltage	I _F = 60 mA	V_{F}	-	1.25	1.65	V
Reverse current	V _R = 6 V	I _R	-	0.01	10	μA
Capacitance	V _R = 0 V, f = 1 MHz	Co	-	13	-	pF
OUTPUT						
Collector emitter capacitance	V _{CE} = 5 V, f = 1 MHz	C _{CE}	-	5.2	-	pF
Collector emitter leakage current	V _{CE} = 10 V	I _{CEO}	-	5	100	nA
COUPLER						
Collector emitter saturation voltage	$I_F = 10 \text{ mA}, I_C = 2.5 \text{ mA}$	V _{CEsat}	-	0.25	0.4	V
Coupling capacitance		C _C	-	0.4	-	pF

Note

• Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO							
PARAMETER	TEST CONDITION	SYMBOL	BIN	MIN.	TYP.	MAX.	UNIT
	10 4 1/ 5 1/	CTR	3	100	-	200	%
1 //	$I_F = 10 \text{ mA}, V_{CE} = 5 \text{ V}$	CTR	4	160	-	320	%
I _C /I _F	1 - 1 m	CTR	3	34	70	-	%
	$I_F = 1 \text{ mA}, V_{CE} = 5 \text{ V}$	CTR	4	56	90	-	%

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SWITCHING CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
NON-SATURATED						
Rise time	I_F = 10 mA, V_{CC} = 5 V, T_A = 25 °C, R_L = 75 Ω	t _r	-	2	-	μs
Fall time	$I_F = 10 \text{ mA}, V_{CC} = 5 \text{ V}, T_A = 25 ^{\circ}\text{C}, R_L = 75 \Omega$	t _f	-	2	-	μs
Turn-on time	I_F = 10 mA, V_{CC} = 5 V, T_A = 25 °C, R_L = 75 Ω	t _{on}	-	3	-	μs
Turn-off time	I_F = 10 mA, V_{CC} = 5 V, T_A = 25 °C, R_L = 75 Ω	t _{off}	-	2.3	-	μs
Cut-off frequency	$I_F = 10 \text{ mA}, V_{CC} = 5 \text{ V}, T_A = 25 ^{\circ}\text{C}, R_L = 75 \Omega$	f _{ctr}	-	250	-	kHz
SATURATED						
Rise time	V_{CC} = 5 V, T_A = 25 °C, R_L = 1 k Ω , I_F = 10 mA	t _r	-	3	-	μs
Fall time	$V_{CC} = 5 \text{ V}, T_A = 25 \text{ °C}, R_L = 1 \text{ k}\Omega, I_F = 10 \text{ mA}$	t _f	-	14	-	μs
Turn-on time	$V_{CC} = 5 \text{ V}, T_A = 25 ^{\circ}\text{C}, R_L = 1 \text{k}\Omega, I_F = 10 \text{mA}$	t _{on}	-	4.2	-	μs
Turn-off time	$V_{CC} = 5 \text{ V}, T_A = 25 \text{ °C}, R_L = 1 \text{ k}\Omega, I_F = 10 \text{ mA}$	t _{off}	-	23	-	μs

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Climatic classification	According to IEC 68 part 1		55 / 100 / 21	
Pollution degree	According to DIN VDE 0109		2	
Comparative tracking index	Insulation group IIIa	CTI	175	
Maximum rated withstanding isolation voltage	According to UL1577, t = 1 min	V _{ISO}	4420	V_{RMS}
Tested withstanding isolation voltage	According to UL1577, t = 1 s	V _{ISO}	5300	V _{RMS}
Maximum transient isolation voltage	According to DIN EN 60747-5-5	V _{IOTM}	10 000	V _{peak}
Maximum repetitive peak isolation voltage	According to DIN EN 60747-5-5	V _{IORM}	890	V _{peak}
Isolation resistance	$T_{amb} = 25 ^{\circ}\text{C}, V_{IO} = 500 \text{V}$	R _{IO}	≥ 10 ¹²	Ω
Isolation resistance	T _{amb} = 100 °C, V _{IO} = 500 V	R _{IO}	≥ 10 ¹¹	Ω
Output safety power		P _{SO}	400	mW
Input safety current		I _{SI}	275	mA
Input safety temperature		T _S	175	°C
Creepage distance			≥8	mm
Clearance distance			≥ 8	mm
Insulation thickness		DTI	≥ 0.4	mm

Note

• As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

30

20

10

I_c (mA)

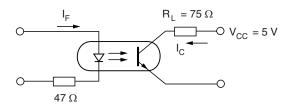
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10 mA

6 mA

4 mA 2 mA

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)



isfh615a_01

Fig. 2 - Linear Operation (without Saturation)

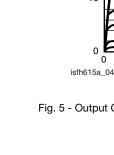
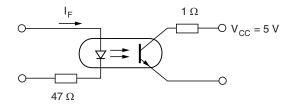


Fig. 5 - Output Characteristics (Typ.) Collector Current vs. Collector Emitter Voltage

 $V_{CE}(V)$



isfh615a_02

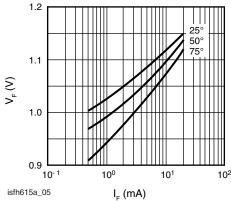


Fig. 6 - Diode Forward Voltage (Typ.) vs. Forward Current



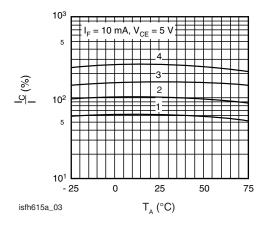


Fig. 4 - Current Transfer Ratio (Typ.) vs. Temperature

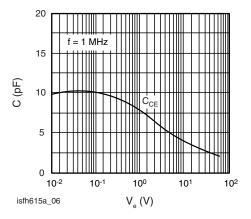


Fig. 7 - Transistor Capacitance (Typ.) vs. Collector Emitter Voltage

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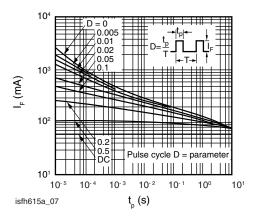
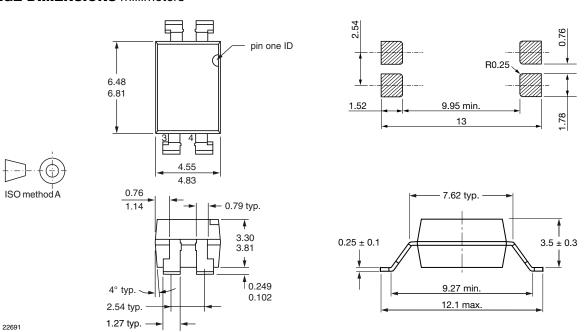


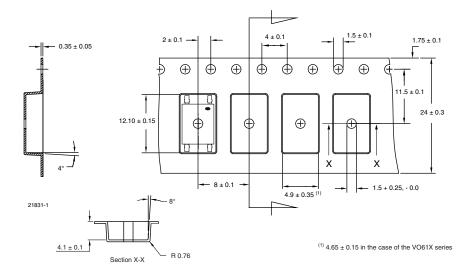
Fig. 8 - Permissible Pulse Handling Capability Forward Current vs. Pulse Width

PACKAGE DIMENSIONS millimeters

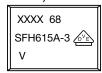


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SMD-4, Option 8



PACKAGE MARKING (example of SFH615A-3X018T)



Notes

- XXXX = LMC (lot marking code)
- VDE logo is only marked on option 1 parts
- Tape and reel suffix (T) is not part of the package marking

TAPE AND REEL PACKING	
TYPE	UNITS/REEL
SMD-4	1000

SOLDER PROFILES

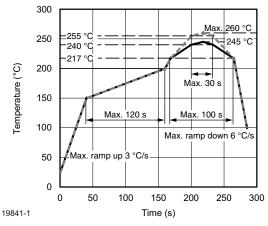


Fig. 9 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020 for SMD Devices

HANDLING AND STORAGE CONDITIONS

ESD level: HBM class 2 Floor life: unlimited

Conditions: T_{amb} < 30 °C, RH < 85 %

Moisture sensitivity level 1, according to J-STD-020

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